

AIT-PID における重水素プラズマの生成 とそのPWI研究への応用

- (1) AIT-PID における高熱流重水素プラズマの生成
- (2) 重水素プラズマータングステン系における熱伝達係数評価
- (3) 重水素プラズマ中におけるタングステンへの熱パルスの効果
- (4) タングステンへの重水素プラズマの重照射の準備

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核融合エネルギーフォーラム プラズマ物理クラスター平成25年度合同研究会
平成25年8月29－30日 於 つくばサイエンスインフォメーションセンター会議室

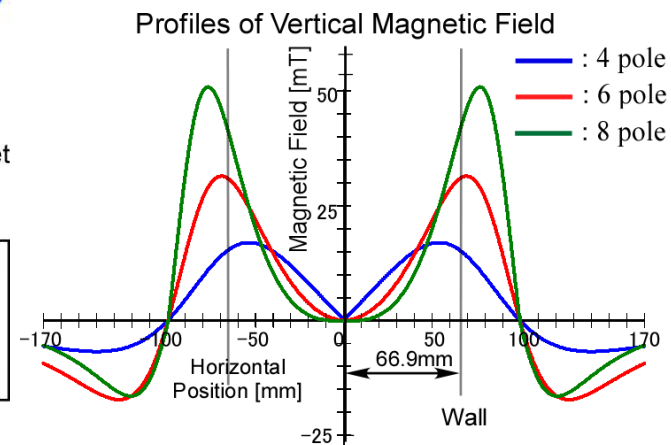
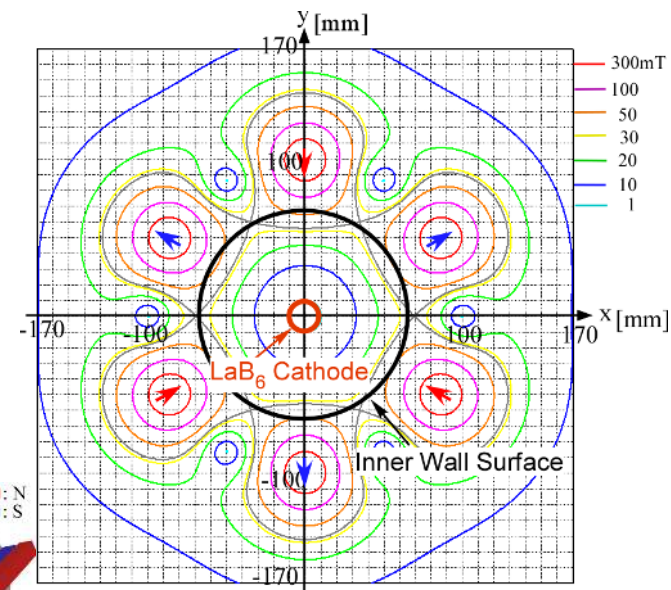
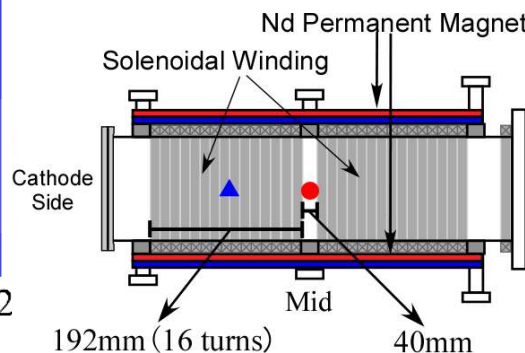
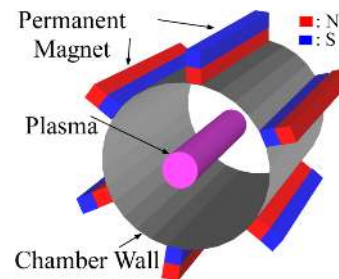
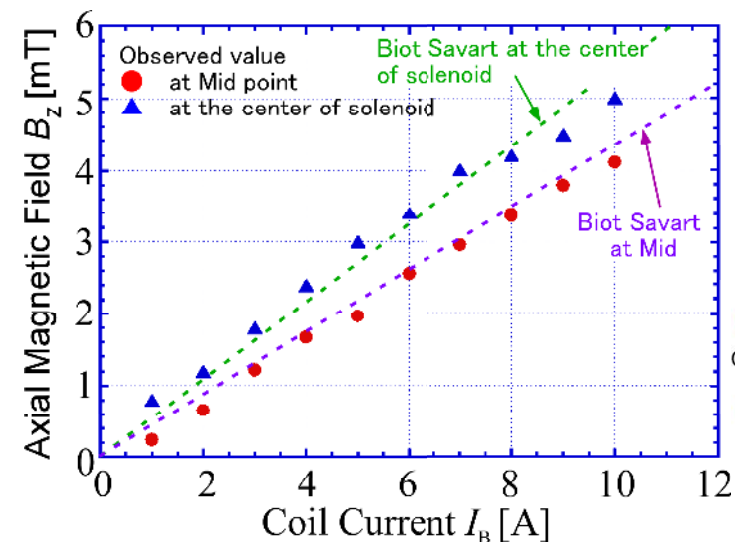
Magnetic Structure in AIT-PID

Usually a **strong magnetic field** more than roughly 0.1T has been employed in linear plasma devices for the radial confinement of produced plasma.

The consumed electric power for energizing the magnetic coils is sometimes very large.

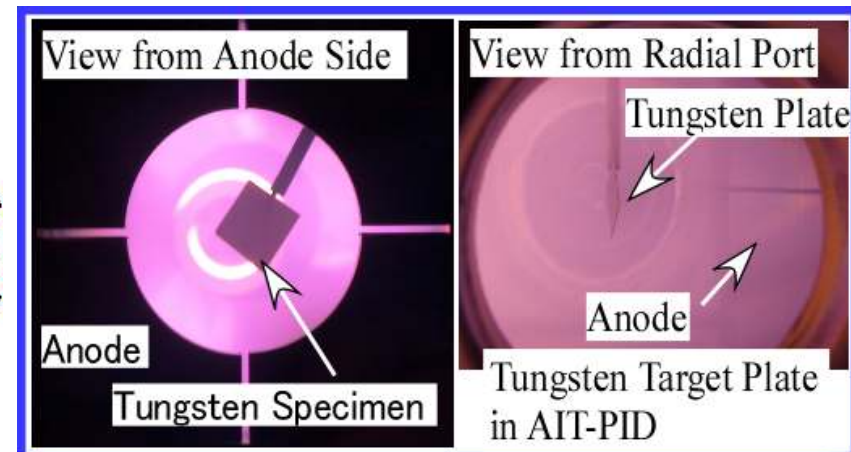
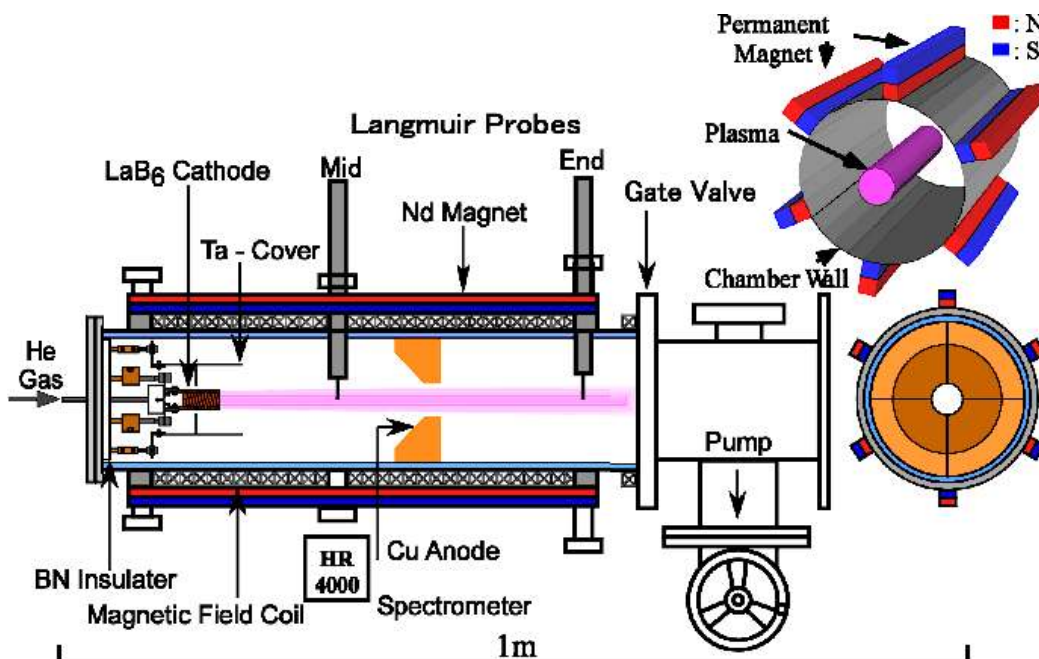
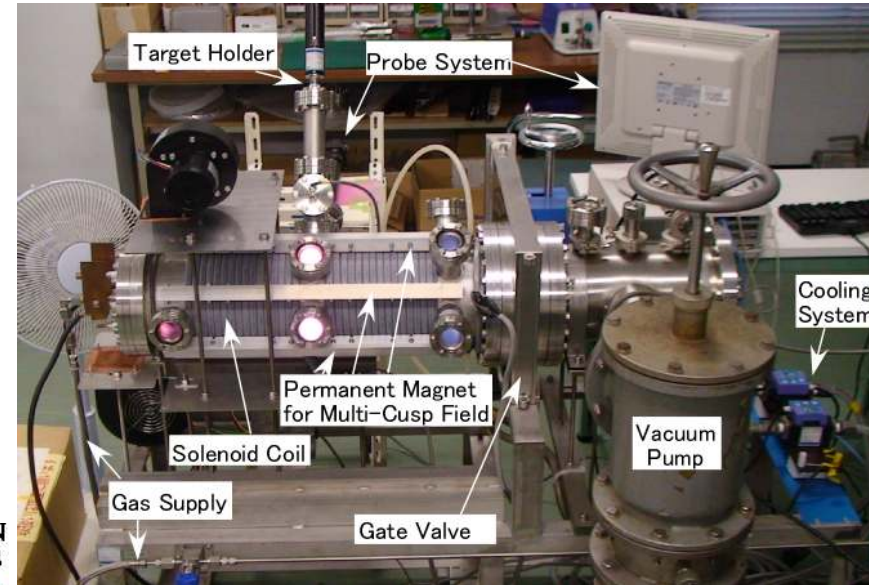
Not only a contribution to **power saving compactness**, but also a favorable effect on the maintenance of directly heated LaB_6 ceramic cathode have been obtained by a very weak Lorentz stress on LaB_6 solenoid.

Additional Weak Axial Magnetic Field



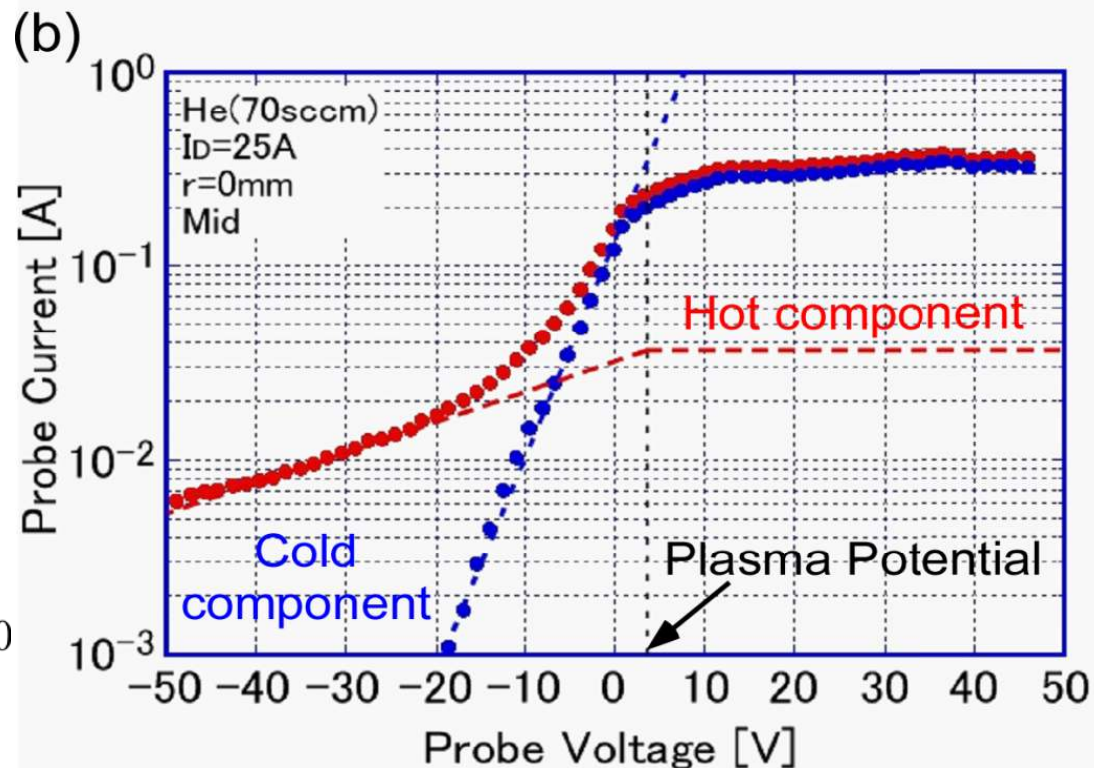
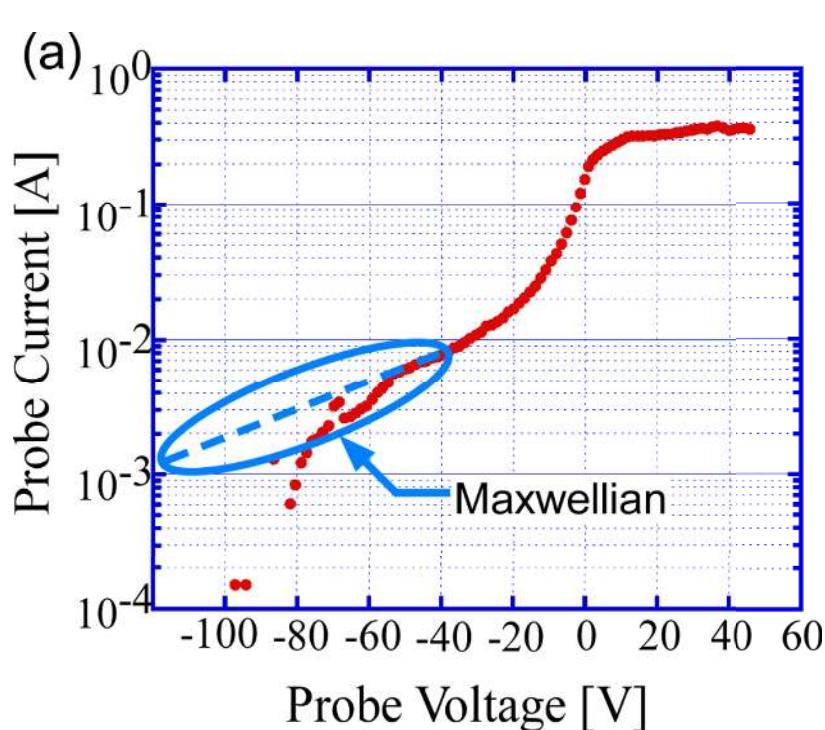
Characterization of AIT-PID Plasmas

Plasma Density $> 1 \times 10^{18} \text{ m}^{-3}$
 Electron Temperature : 4 eV
 with 10% Hot Component (40 eV)
 Floating Voltage : $\sim 40 \text{ V}$
 Plasma Potential : $\sim 5 \text{ V}$
 Ion Flux : $1 \times 10^{22} \text{ m}^{-2} \text{ s}^{-1}$



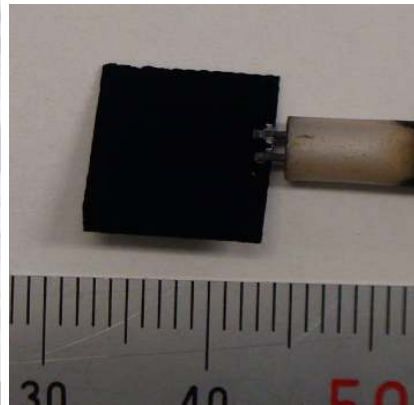
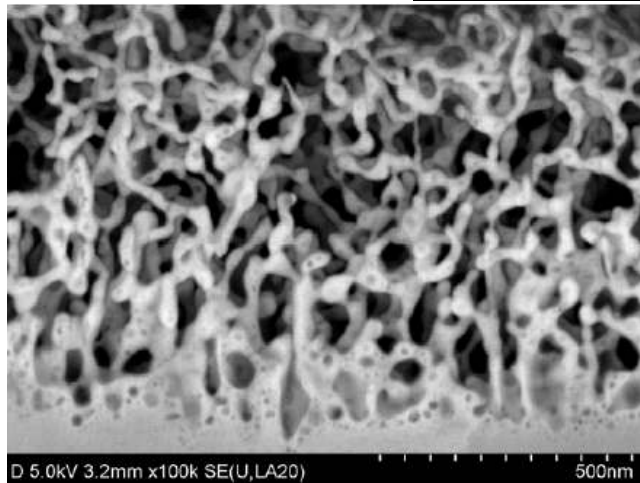
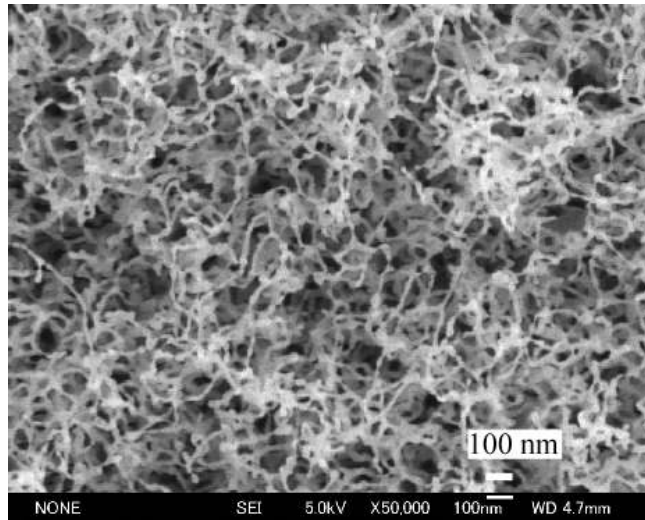
Hot Electrons

- AIT-PID contains **hot electron** component:
10 % with $T_{eh} \sim 40$ eV, while $T_{ec} \sim 4$ eV.
- The energy distribution is not a complete Maxwellian, but has a cut around the discharge voltage.



Nanostructure on Tungsten Surface

物理学会誌
9月号 解説



Finding of Nanostructure Formation on Tungsten Surface at 2006

Plasma and Fusion Research: Rapid Communications

Volume 1, 051 (2006)

Formation of Nanostructured Tungsten with Arborescent Shape due to Helium Plasma Irradiation

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(Received 12 September 2006 / Accepted 24 September 2006)

Deeply nanostructured tungsten with an arborescent shape was found for the first time to be formed on tungsten-coated graphite by a high-flux helium plasma irradiation at surface temperatures of 1250 and 1600 K, an incident ion energy of 12 eV (well below the physical sputtering threshold) and a helium ion fluence of $3.5 \times 10^{27} \text{ m}^{-2}$.

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Keywords: plasma-material interaction, nanostructured tungsten, helium bombardment

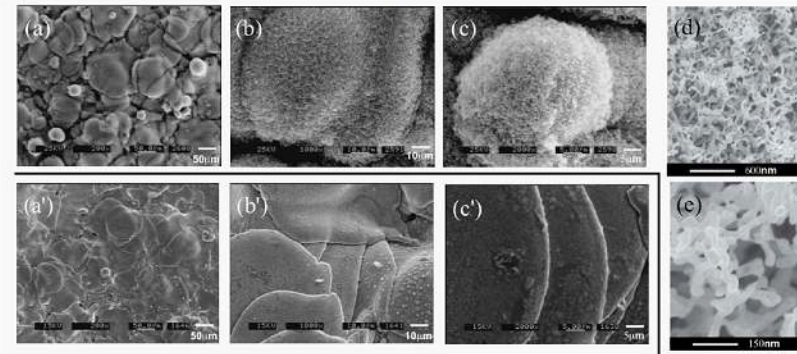
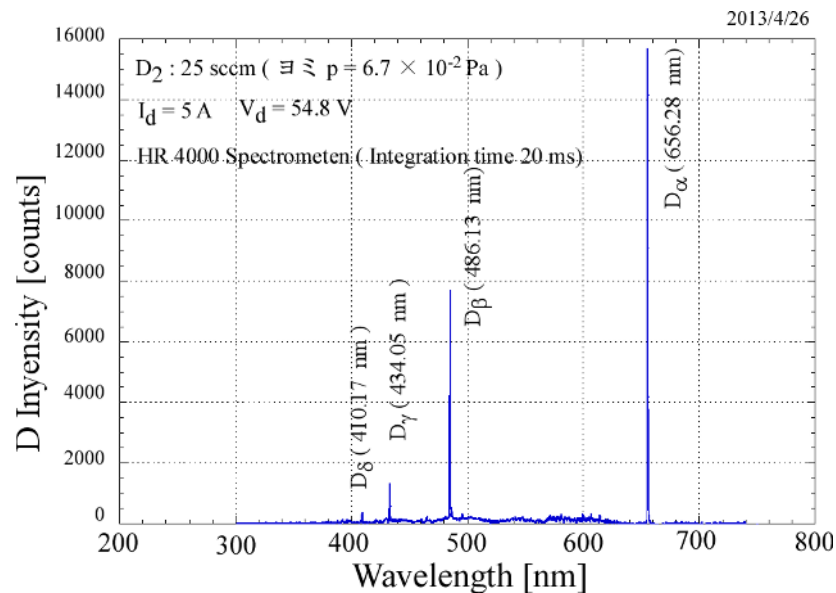


Fig. 1 (a)~(c): SEM photographs of W-C surface after and (a')~(c') before helium plasma irradiation at a surface temperature of 1250 K, a fluence of $3.5 \times 10^{27} \text{ m}^{-2}$ and an ion incident energy of 12 eV. (d) and (e): photographs taken by FE-SEM with a high spatial resolution. The line of sight is normal to the samples.

S. Takamura et al.:

- (1) Plasma Fusion Res. **5** (2010) 039 : Deepening of Floating Potential
- (2) Proc. 38th EPS Conf. on Plasma Phys. (2011) O1.302: Outstanding Properties
- (3) J. Nucl. Mater. **415** (2011) S100 : Effect of Temperature Excursion; J. Nucl. Mater. **438** (2013) S814 : Temp. Measurement
- (4) Plasma Fusion Res. **6** (2011) 1202005; Plasma Sci. & Technol. **15** (2013) 161 : Recovery of W Surface
- (5) Nucl. Fusion **53** (2013) 1232001 : Effect of Particle Emission

重水素プラズマ生成



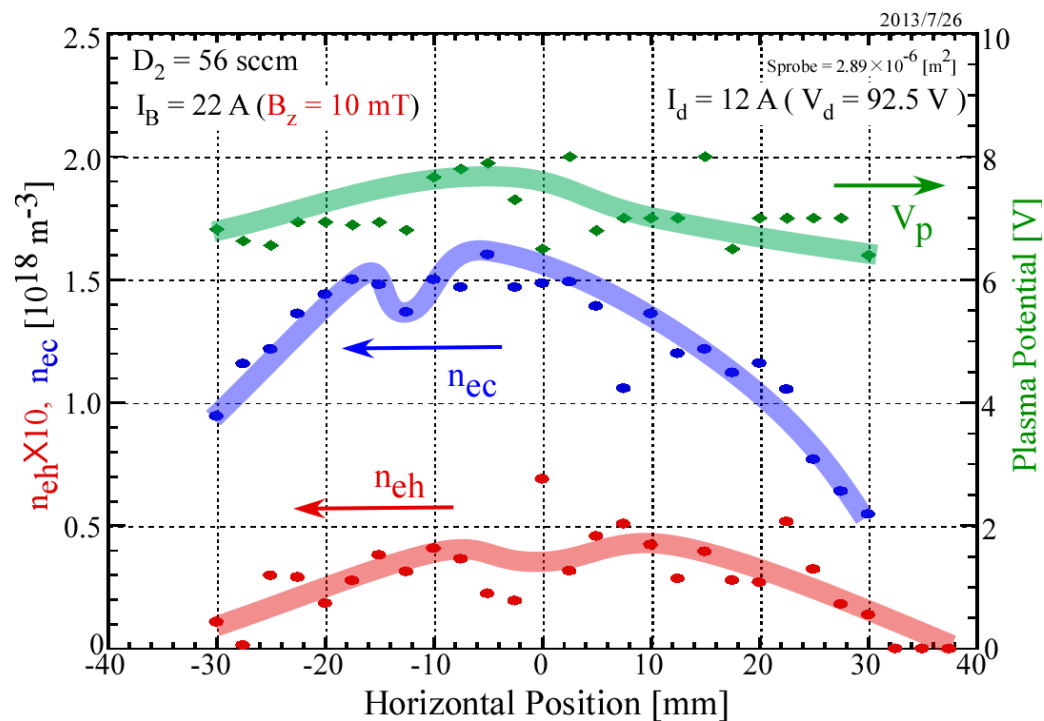
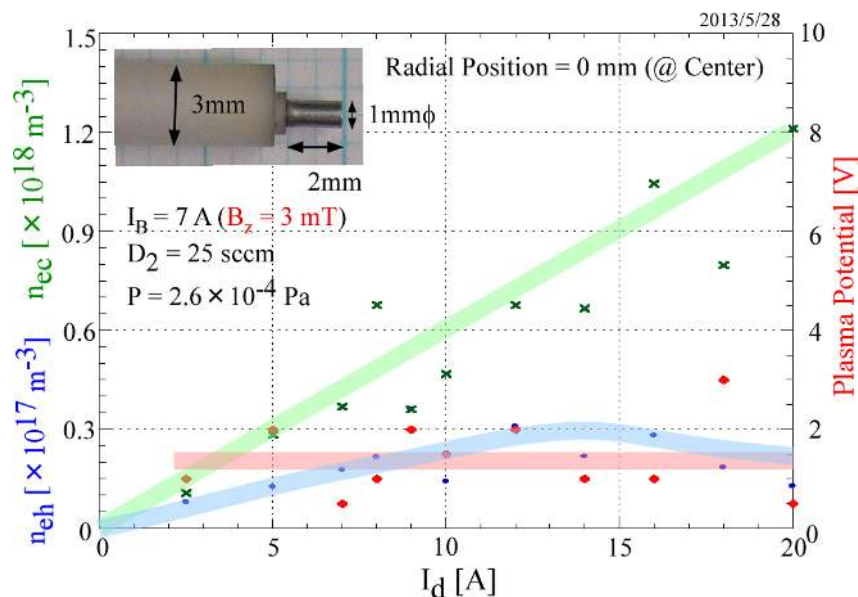
Dプラズマ

密度: $\geq 1 \times 10^{18} \text{ m}^{-3}$

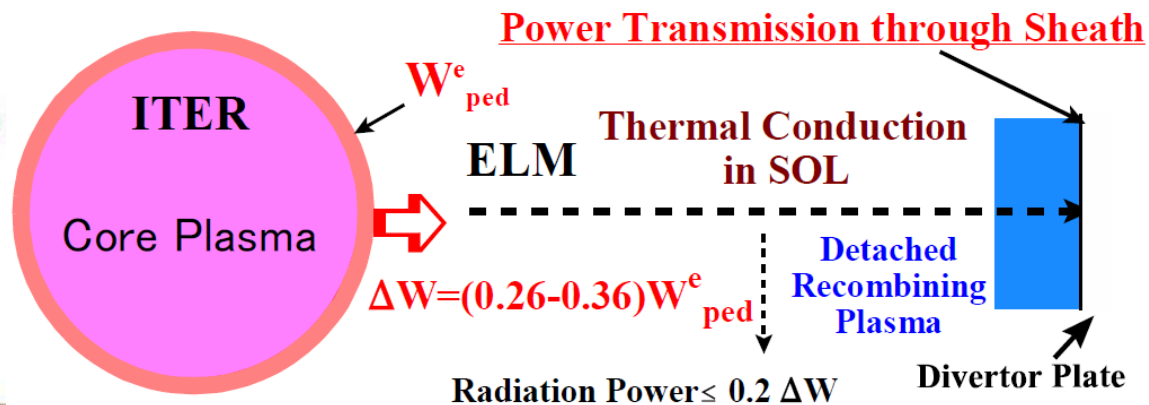
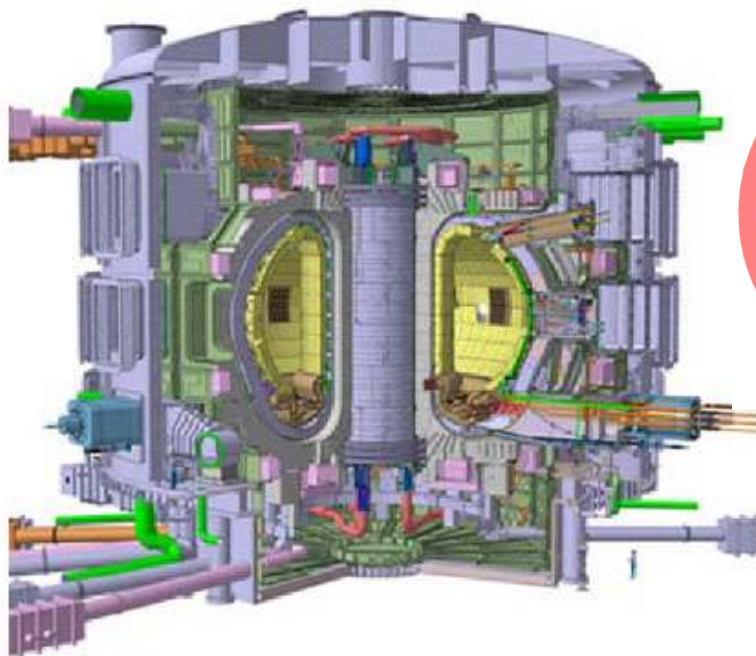
Tec : ~ 3 eV; Teh : 20 ~ 30 eV

α (abundance) $\lesssim 5 \%$

V_p : +2 ~ +7 V



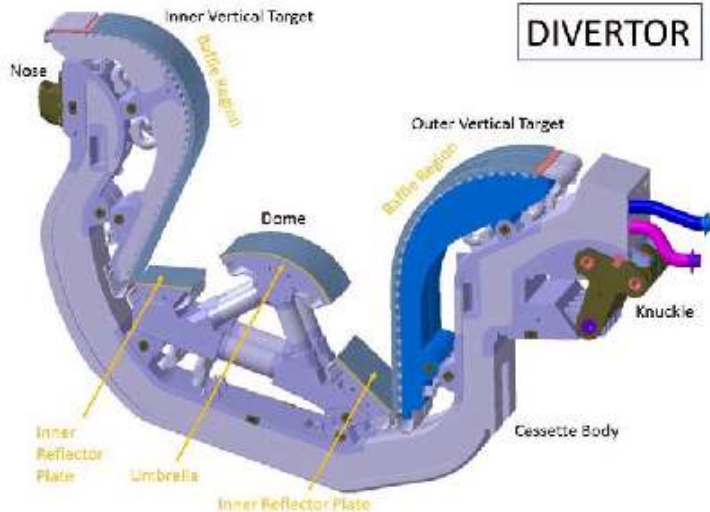
Power onto Plasma-Facing Surface



Steady Power Flux: 10 ~ 20 MW/m²

Transient Energy Density: 0.2 ~ 2.0 MJ/m²

DIVERTOR



Power Transmission Factor is a key measure to determine the power flux to the plasma-facing surface !

Edge
Plasma
Physics

Sheath
Physics

Material
Engineering

Present Status for Power Transmission Factor (PTF)

S. Masuzaki et al.:
J. N. M. **223** (1995) 286

Maxwellian Plasmas
Normal Tungsten W

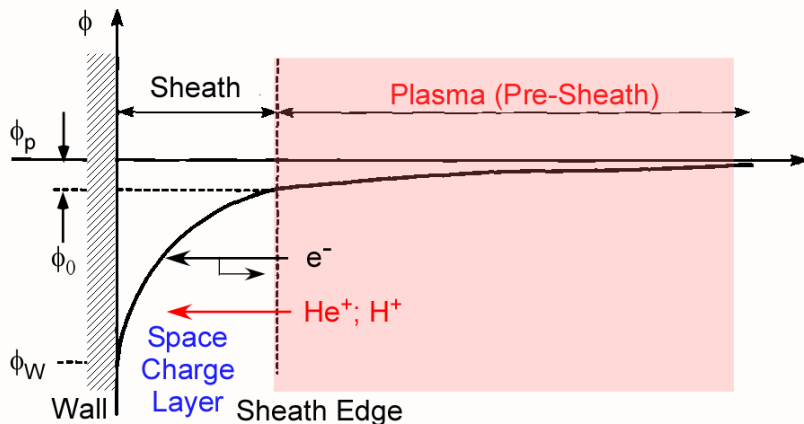
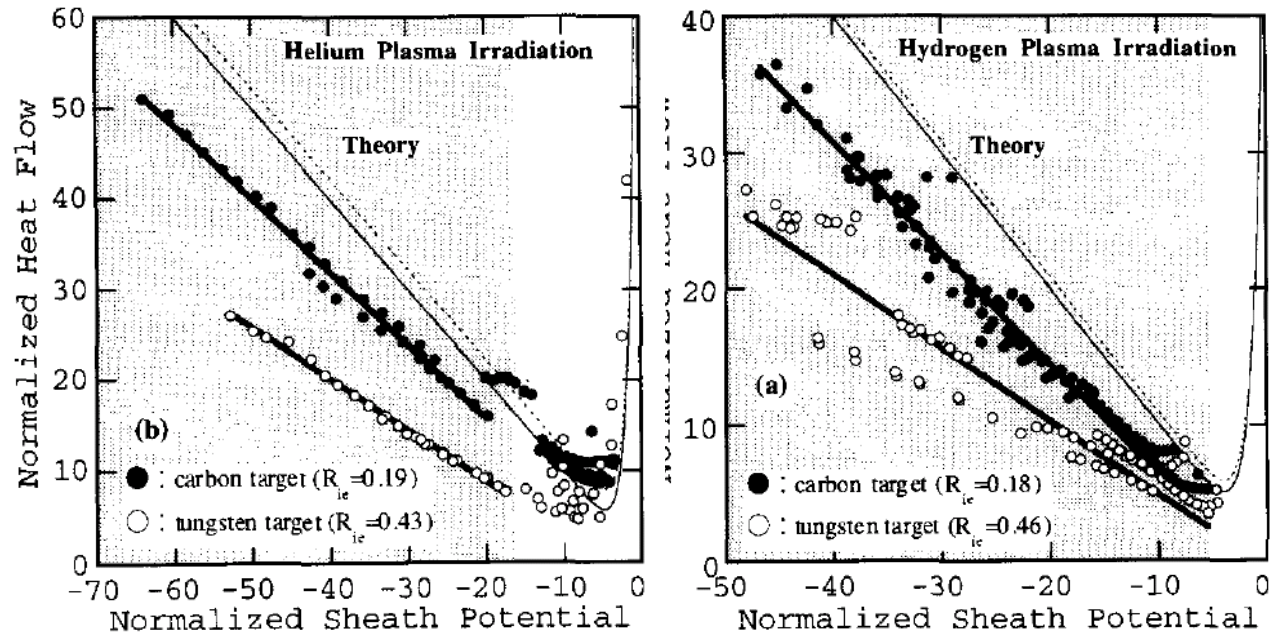
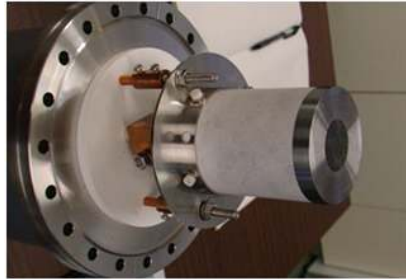


Fig. 6. The normalized plasma heat flows from experiment and theory. Thin solid curves are obtained from Eq. (3), simple sheath theory, that does not include the effects of ion reflection and surface recombination. Dashed lines come from Eq. (5) with $R_{ie} = 0$ and typical electron temperatures $T_e = 15$ eV for hydrogen plasma and 10 eV for helium plasma are substituted, respectively. The hatched regions are the ion saturation region, in which ion contribution to the heat flow dominate. The experimental data points are fitted by the bold solid lines. (a) Hydrogen plasma $\rightarrow$ carbon or tungsten, (b) helium plasma $\rightarrow$ carbon or tungsten.

Calibration

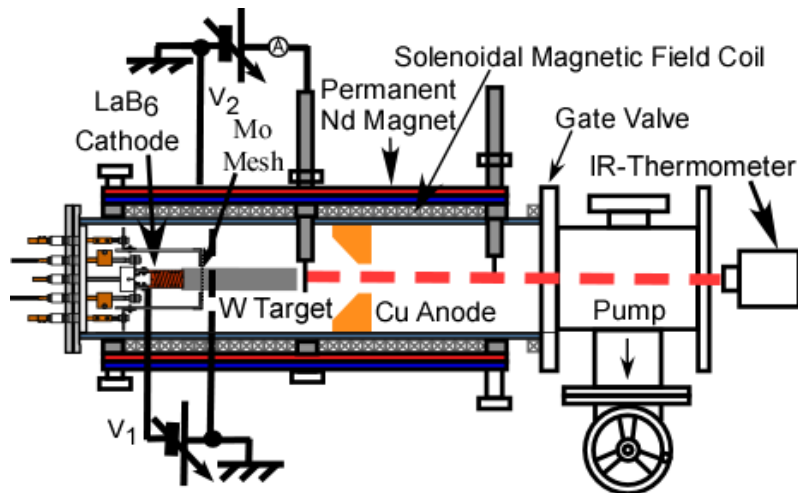
for the Relation between T_W and P_{input}



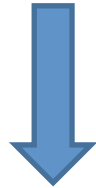
Electron Beam Source



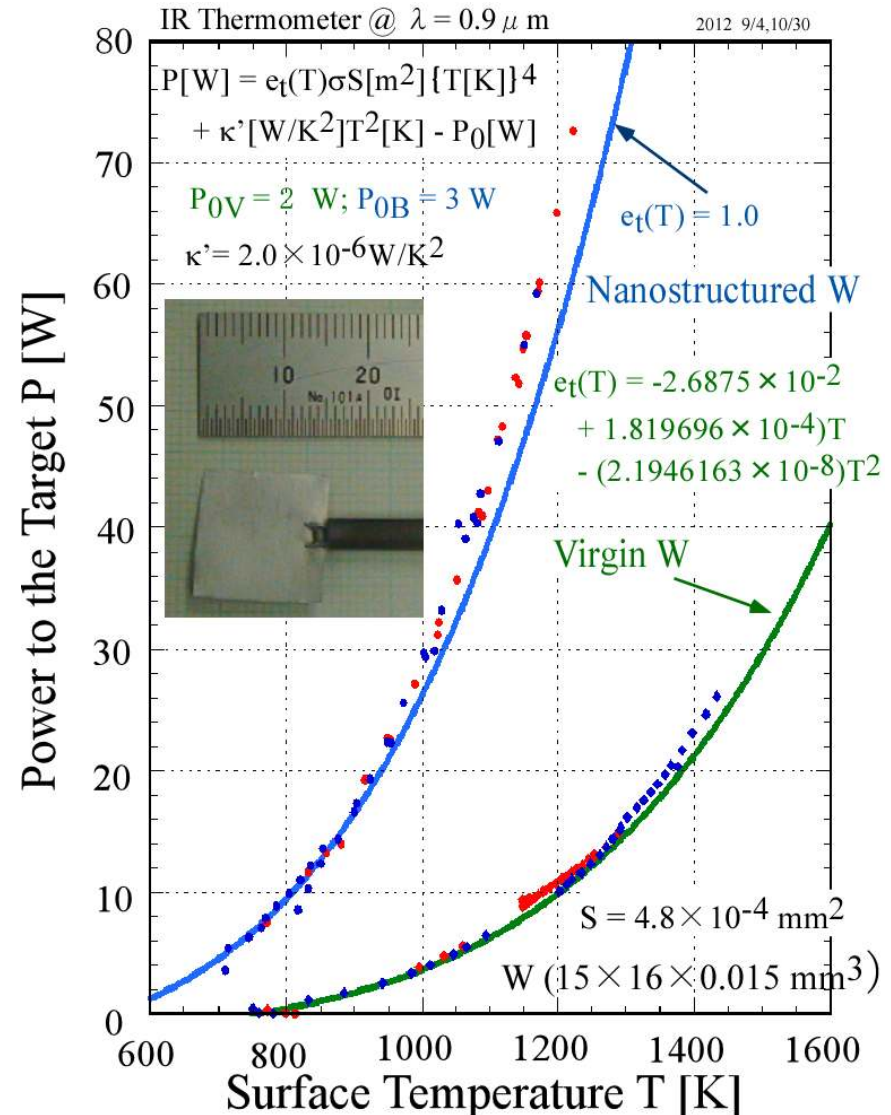
IR-Thermometer



Tungsten Temp.



Input Power



Modified PTF Analysis (He⁺ - W)

$$eQ_i / j^+ = e|\phi_P - \phi_W|(1 - R_{iE}) + e\phi_i - e\phi_W \gamma_{Aug}$$

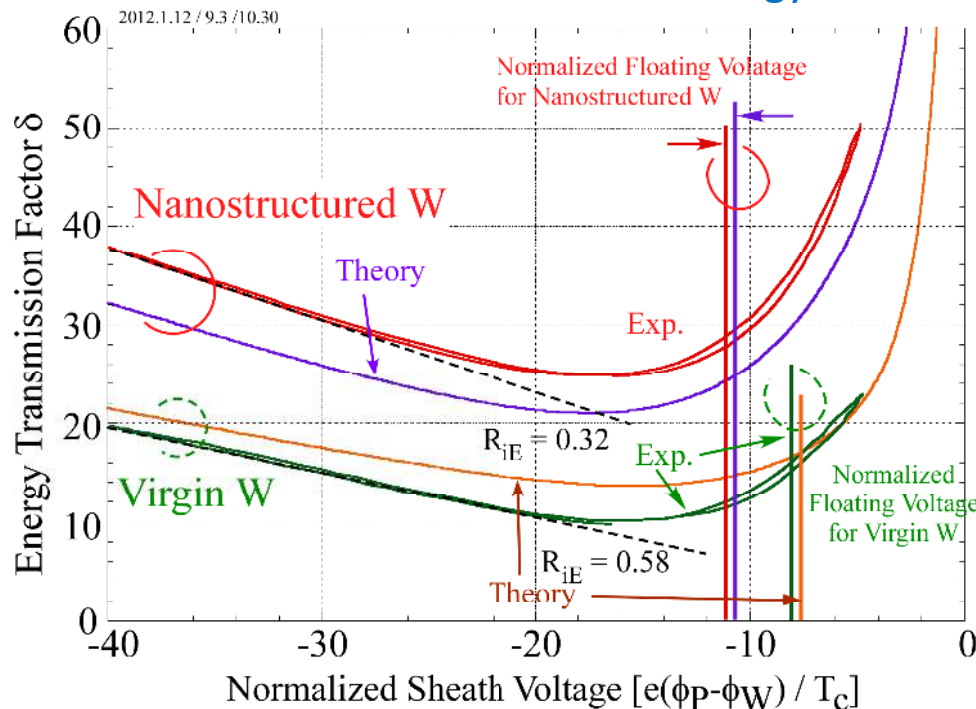
Impact Energy

Effective Surface Recombination Energy

$$eQ_e / j^+ = 2T_c(1 - \alpha)\chi_c \exp\left(-\frac{e(\phi_P - \phi_W)}{T_c} + \frac{T_{eff}}{2T_c}\right) + (2T_h - e\phi_W \gamma_e)\alpha\chi_h \exp\left(-\frac{e(\phi_P - \phi_W)}{T_c\beta} + \frac{T_{eff}}{2T_c\beta}\right)$$

Bulk Electron Energy

Effective Hot Electron Energy



Where γ_{Aug} : Auger electron emission coef.,
 γ_e : SEE coef.
 $e\phi_W$: Work function of W.

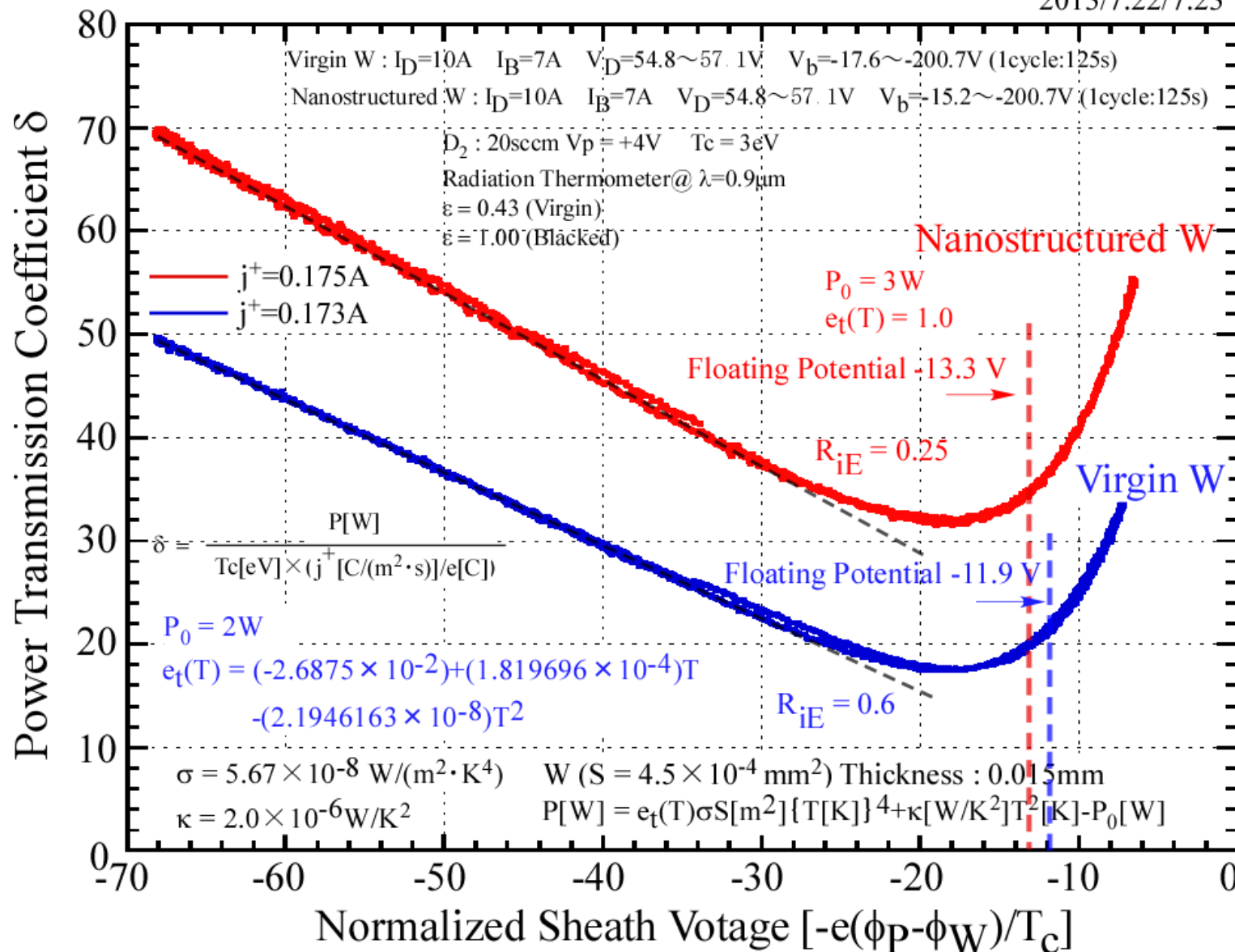
$$\gamma_e(T_h = 30\text{eV}) \approx 0.48$$

$$\gamma_{Aug} = 0.28$$

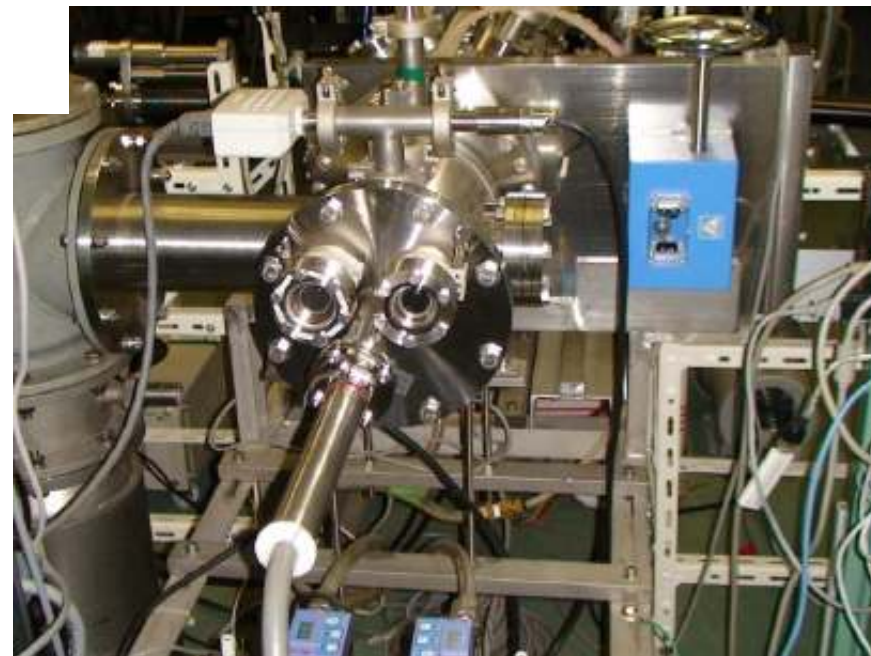
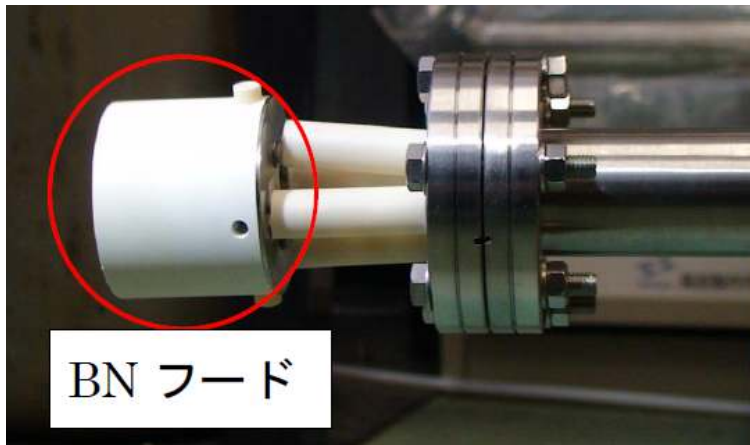
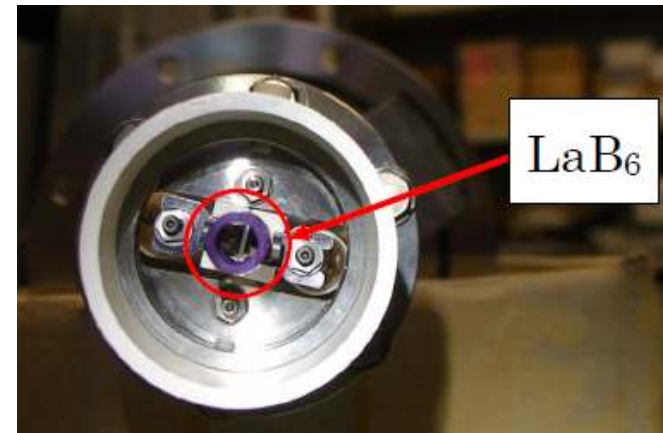
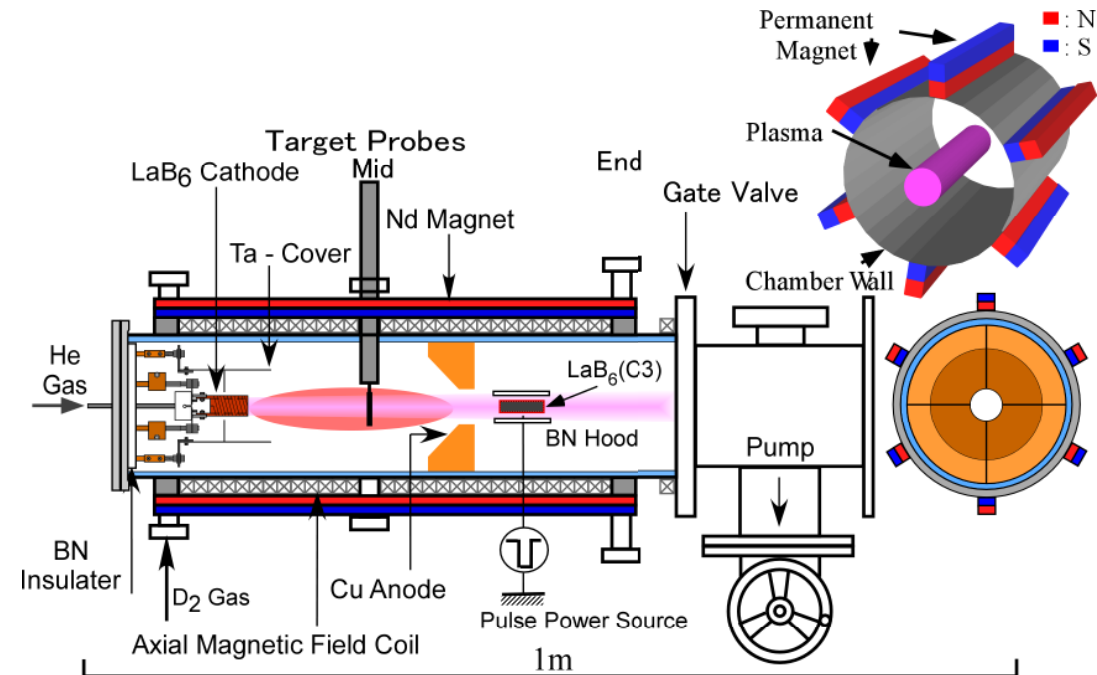
Still we have some gap
 between experimentally obtained PTF and
 theoretical analysis !

Dプラズマ-W系熱伝達係数

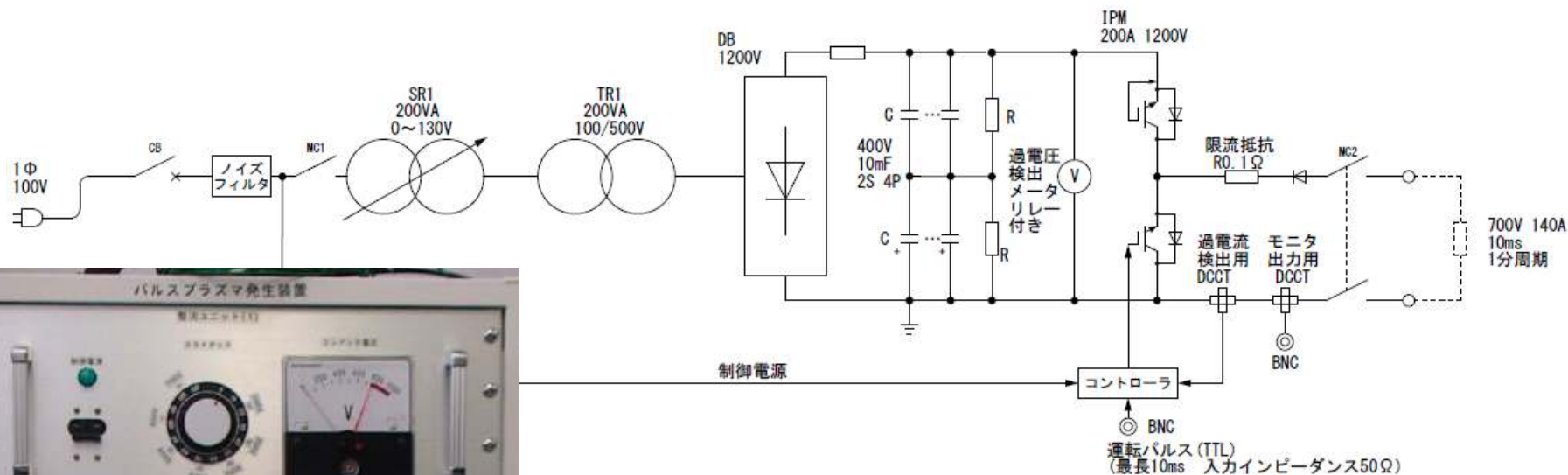
2013/7.22/7.23



Dプラズマ中Wへの熱パルス



パルス電源



パルスプラズマ発生装置 単線接続図

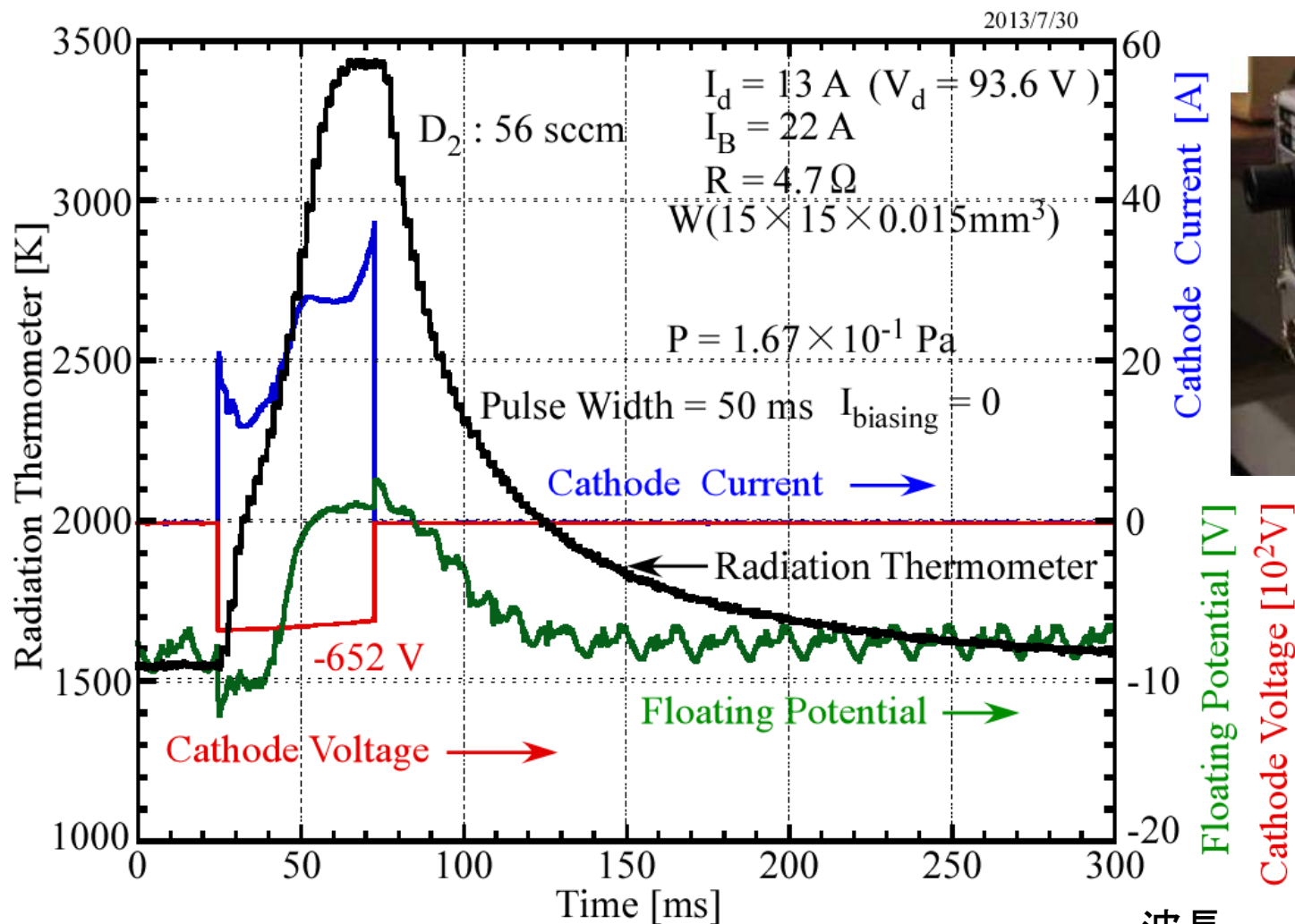
仕様

出力電圧: 750 V; 出力電流: 140 A
出力パワー: 105 kW

パルス長: ≤ 50ms; 周期: 1分



Dプラズマ熱パルスに対するWの応答



分光放射率
 $\varepsilon = 0.42$ (固定)

$E \sim 0.1 \text{ MJ/m}^2$

Input Power $\sim 15 \text{ kW}$

放射温度計(チノー IR-CAS3CS)

波長: $0.9 \mu\text{m}$
温度範囲: $600 \sim 3000^\circ\text{C}$
応答時間: 3 ms (95 %)

Wの分光放射率 $e(\lambda, T)$

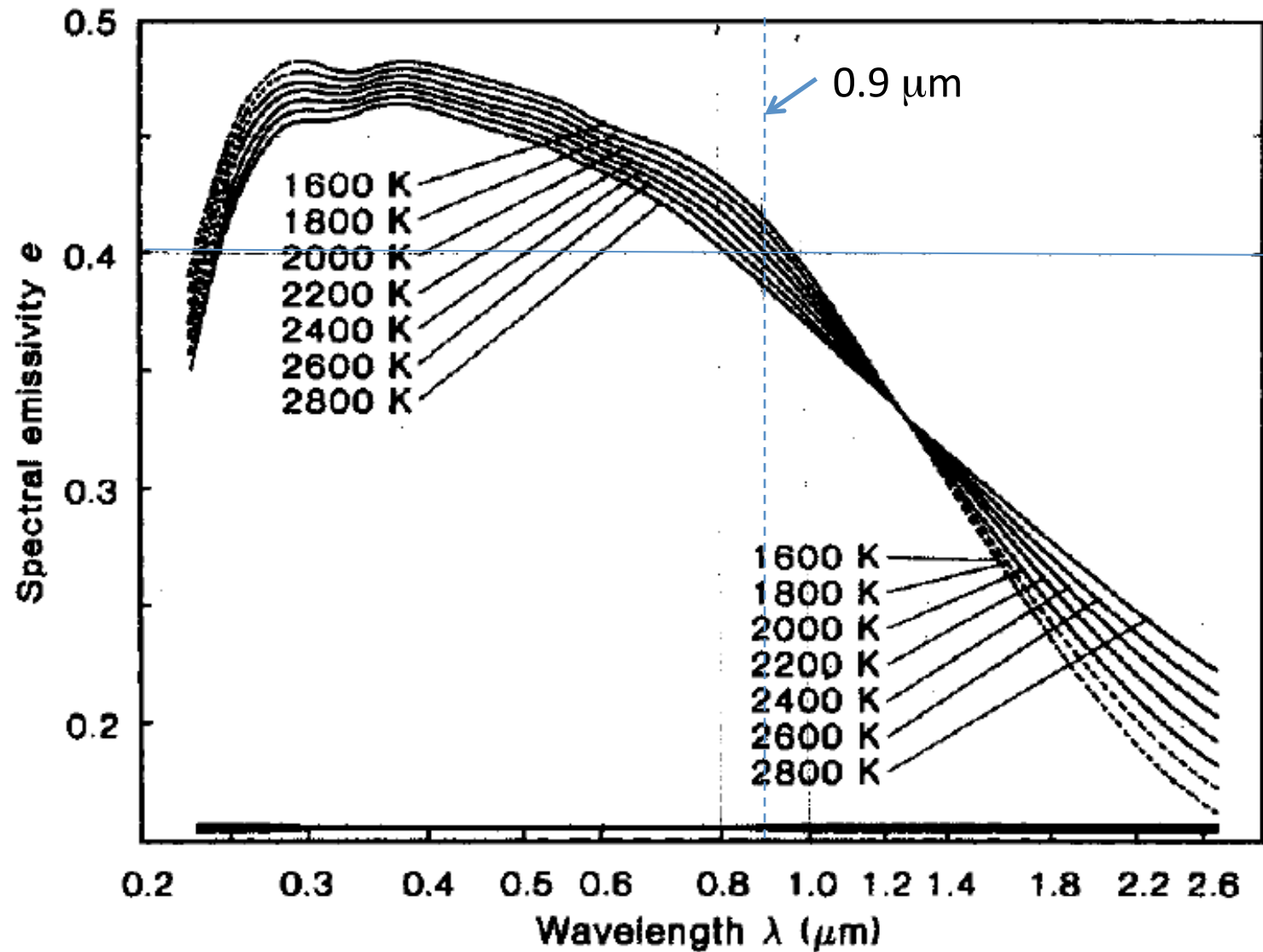
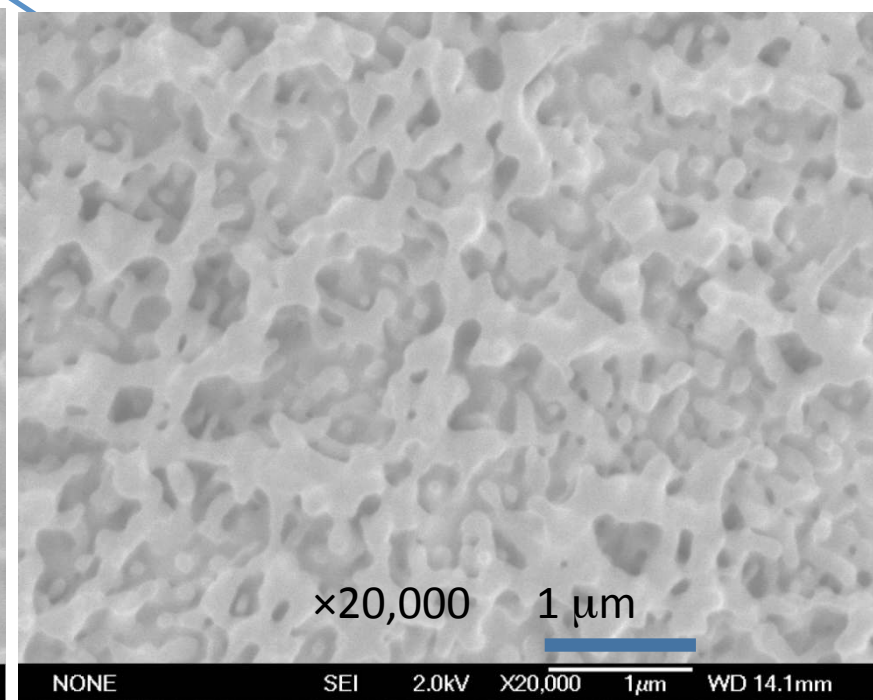
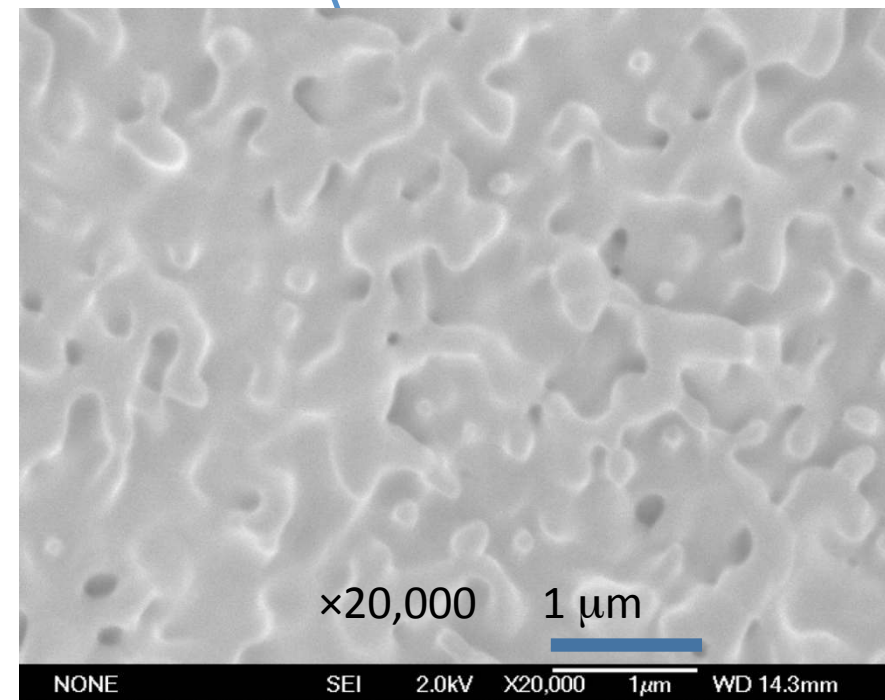
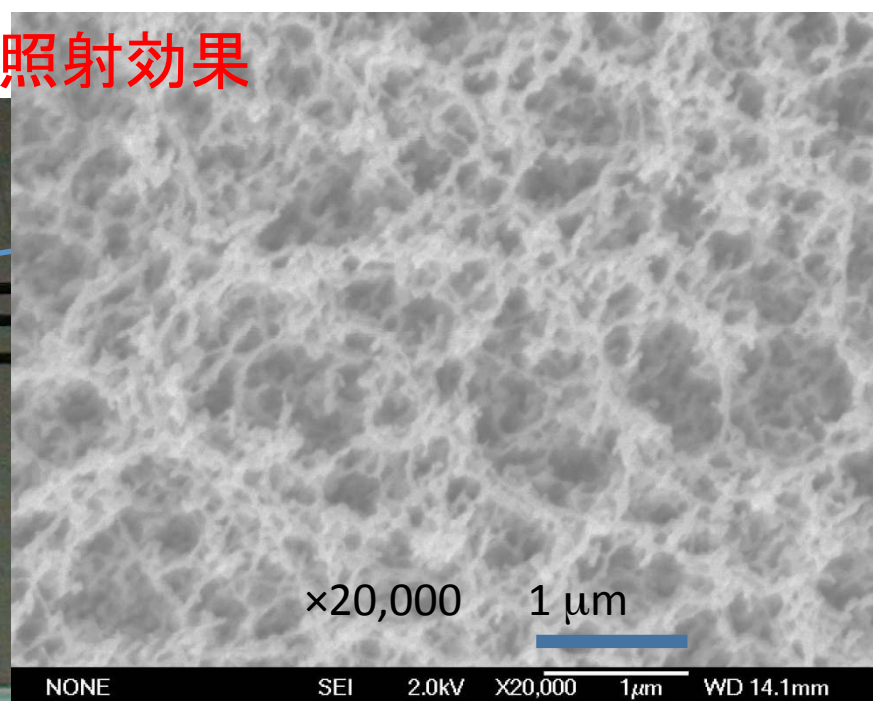
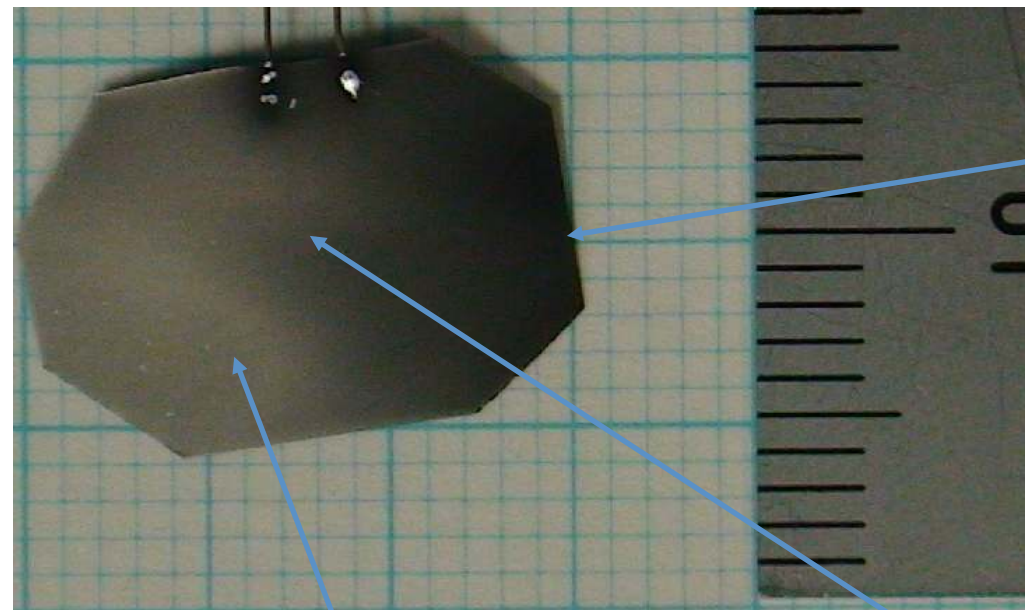
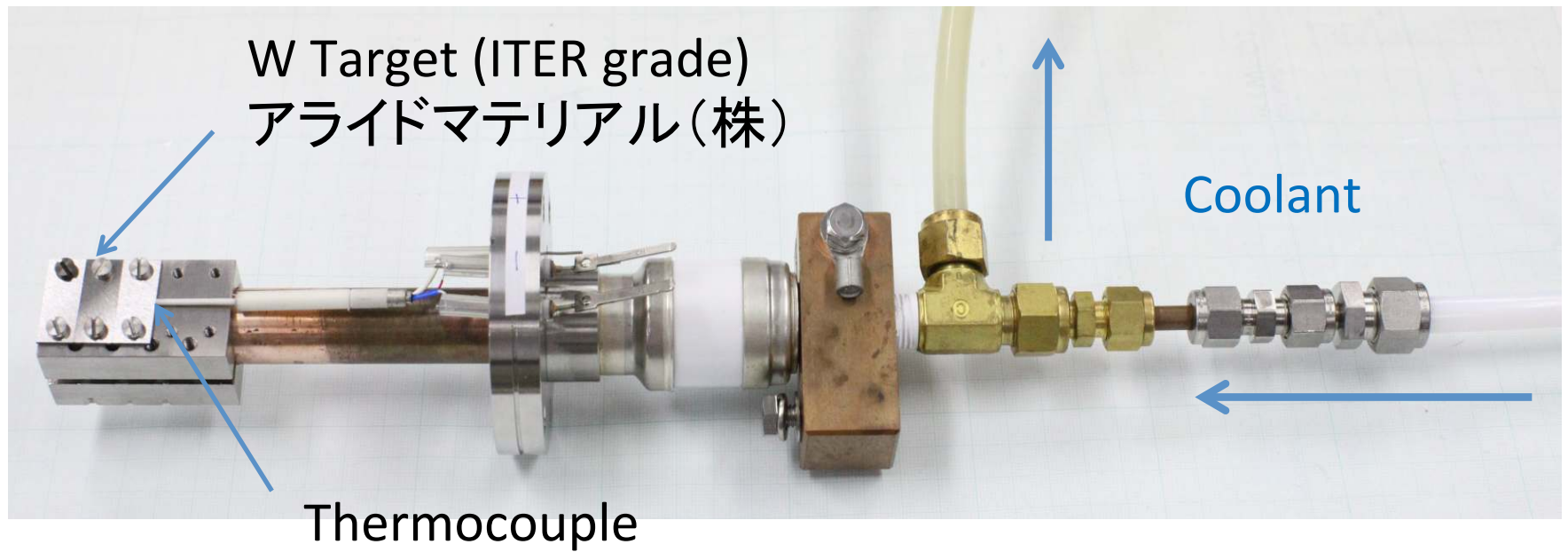


FIGURE 1.20. Spectral emissivity of tungsten according to de Vos [1.37].

繊維状ナノ構造形成Wへの熱パルス照射効果



WへのDプラズマ重照射 準備



ま と め

- (1) 高熱流重水素プラズマの生成
- (2) 重水素プラズマ－タングステン系における熱伝達係数の実験的評価（Virginと 黒色化 Wでの相違）
- (3) 重水素プラズマ中におけるタングステンへの熱パルスの効果：3000 Kを超える昇温。浮遊電位の低下の観測
- (4) タングステンへの重水素プラズマの重照射のための直接冷却ターゲットホルダーの製作

今後の予定：

- (1) 熱伝達係数の理論的評価
- (2) 熱パルスによる溶融過程の調査
- (3) 製造方法の異なるタングステンへの重水素プラズマの重照射効果